













• •



Bill of Materials

Designator	Description V	alue	Q
C1	Electrolytic capacitor 16v/50v	10μF	1
C2, C3	Ceramic or tantalum capacitor	100nF	2
IC1, IC2	4-bit D-Type Register with 3 state outputs 74	LS173	2
P1	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 16k	16p	1
P2	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 32x	32p	1
Р3	Socket Header, THT, pitch 2.54mm, Dual Row, Vertical,	24p	1
RN1	Resistor array 8 elements,9 pins	1K	1



Assembly List

Designator	Description	Value
C1	Electrolytic capacitor 16v/50v	10µF
C2	Ceramic or tantalum capacitor	100nF
C3	Ceramic or tantalum capacitor	100nF
IC1	4-bit D-Type Register with 3 state outputs	74LS173
IC2	4-bit D-Type Register with 3 state outputs	74LS173
P1	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 16p	16p
P2	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 32p	32p
Р3	Socket Header, THT, pitch 2.54mm, Dual Row, Vertical, 24r	24p
RN1	Resistor array 8 elements,9 pins	1K